

L Number	Hits	Search Text	DB	Time stamp
1	3222	((("257/213").CCLS.) or (("257/288").CCLS.) or (("257/327").CCLS.) or (("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 18:50
2	2	6175143.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 18:52
3	2	6177712.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 19:45
4	15	(lateral adj2 field adj effect and switching).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 20:35
5	5	((("5629558") or ("5940700") or ("5874767") or ("4485392") or ("6127695")).PN.	USPAT	2002/01/07 20:36
-	0	("dmos.ti,ab. and buried.ti,ab. and depletion.ti,ab.").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:27
-	3	dmos.ti,ab. and buried.ti,ab. and depletion.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:09
-	2	jp-02122672\$-\$\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:02
-	2	jp-08321606\$-\$\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:02
-	78	dmos.ti,ab. and buried.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:09
-	19	dmos.ti,ab. and buried.ti,ab.	USPAT	2002/01/06 15:11
-	0	dmos.ti,ab. and buried.ti,ab. and withstand adj2 voltage.ti,ab.	USPAT	2002/01/06 15:12
-	1	dmos.ti,ab. and buried.ti,ab. and withstand adj2 voltage	USPAT	2002/01/06 15:29
-	392	("257/213").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:29
-	697	("257/288").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:29
-	351	("257/327").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:29

-	441	("257/339").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:30
-	991	("257/355").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:30
-	500	("257/335").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:31
-	13	((("257/213").CCLS.) or (("257/288").CCLS.) or ("257/327").CCLS.) or ("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)) and buried.clm. and (dmos or dmosfet).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:33
-	74	((("257/213").CCLS.) or (("257/288").CCLS.) or ("257/327").CCLS.) or ("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)) and buried.clm. and (dmos or dmosfet or fet or field adj effect adj transistor or mos or mosfet or nmso or nmosfet or pmos or pmosfet).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 15:34
-	75	((("257/213").CCLS.) or (("257/288").CCLS.) or ("257/327").CCLS.) or ("257/335").CCLS.) or (("257/339").CCLS.) or (("257/355").CCLS.)) and buried.clm. and (dmos or dmosfet or fet or field adj effect adj transistor or mos or mosfet or nmso or nmosfet or pmos or pmosfet).ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 17:55
-	1	5742087.pn. and depletion	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 18:11
-	72	(first adj buried and second adj buried).clm. and (breakdown adj voltage or withstand adj voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 18:13
-	18	(first adj buried and second adj buried).clm. and (breakdown adj voltage or withstand adj voltage) and impurity and switching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 18:27
-	122	(first adj buried and second adj buried) and (breakdown adj voltage or withstand adj voltage)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 10:32
-	987	switching near10 diode and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:09
-	987	(switching near10 diode) and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:09

-	203	(switching adj2 diode) and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:09
-	38	(switching adj2 diode).ti,ab. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:21
-	0	(switching adj2 diode).ti,ab. and 257/\$6.ccls. and galbiati.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:22
-	0	(switching adj2 diode).ti,ab. and 257/\$6.ccls. and ludikhuize.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/06 20:23
-	61	fifth adj impurity.clm. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 08:16
-	18	(fifth adj impurity.clm. and 257/\$6.ccls.) and switching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 08:17
-	43	(first adj impurity near12 second adj impurity) near12 surround\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 10:54
-	6	((first adj impurity near12 second adj impurity) near12 surround\$3) and switching	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 11:42
-	12	(buried adj region near10 gap) and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 11:43
-	3	5874767.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:28
-	298	((slit or gap or opening) near10 buried) and (withstand or breakdown) adj voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:31
-	273	((slit or gap or opening) near10 buried) and (withstand or breakdown) adj voltage and (438/\$6.ccls. or 257/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:33
-	52	((slit or gap) near10 buried) and (withstand or breakdown) adj voltage and (438/\$6.ccls. or 257/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:40
-	14	((slit or gap) near10 buried adj2 (region or layer)) and (withstand or breakdown) adj voltage and (438/\$6.ccls. or 257/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 14:45

-	5	((("257/653").CCLS.) or (("257/654").CCLS.)) and (buried same thickness same (greater or increase\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 17:22
-	0	5629558.PN. and (thick\$4 same buried)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 17:22
-	1	5629558.PN. and thick\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/01/07 17:22



Creation date: 09-05-2003  
Indexing Officer: CPHAN - COUNG PHAN  
Team: OIPEBackFileIndexing  
Dossier: 09834954

Legal Date: 01-09-2002

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Remarks:

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